Electronic Supplementary Information for

Bridging the Gas and Condensed Phases for Metal Atom Encapsulating Silicon- and Germanium-Cage Superatoms: Electrical Properties of Assembled Superatoms

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Contents

Figure S1. Mass spectra of M-Si NCs of M = Lu, Ti, Zr, Hf, V, Nb, and Ta. Figure S2. Plots of ln G versus $T^{-1/2}$ for Ti@Si ₁₆ and Zr@Si ₁₆ assembled films.	S2
	S2
Figure S3 . Plots of ln <i>G</i> versus $T^{-1/2}$ for Ta@Ge ₁₆ assembled films.	S3



Figure S1. Mass spectra of M-Si binary NC anions of (a) M = Lu and cations of M = (b) Ti, (c) Zr, (d) Hf, (e) V, (f) Nb, and (g) Ta. Red arrows indicate the peak corresponding to $M@Si_{16}^{+/-}$.



Figure S2. Plots of ln *G* versus $T^{-1/2}$ relationship for Ti@Si₁₆ and Zr@Si₁₆ assembled films.



Figure S3. Plots of ln *G* versus $T^{-1/2}$ relationship for Ta@Ge₁₆ assembled films based on ES-VRH model.